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Local redox buffering by carbon at low pressures and the formation of moissanite – natural SiC

ANDREI A. SHIRYAEV1,2,* and FABRICE GAILLARD3

1 Institute of Physical Chemistry and Electrochemistry RAS, Leninsky pr. 31, 119071 Moscow, Russia
2 Institute of Geology of Ore Deposits, Petrography, Mineralogy and Geochemistry RAS, Staromonetny per. 35, 119017 Moscow, Russia
*Corresponding author, e-mails: shiryaev@phyche.ac.ru; a_shiryaev@mail.ru
3 CNRS/INSU, Institut des Sciences de la Terre d’Orléans – UMR 6113, Université d’Orléans, Campus Géosciences, 1A rue de la Férérollerie, 41071 Orléans cedex 2, France

Abstract: Grains of natural SiC, moissanite, are encountered in various geological settings. According to thermodynamic calculations and high-pressure experiments, SiC formation requires very reducing conditions, approx. 6–10 orders of magnitude in fO2 more reducing than the present-day mantle redox state. SiC occurrences have motivated several studies but the required extremely reducing conditions remain a major inconsistency that has not been solved. It is shown here that such reducing conditions can be achieved during the ultimate steps of ascent of carbon-saturated melts, when pressure is lower than 100 bars. At these conditions, the redox buffering by carbon can impose fO2 similar to IW-6. Conditions favorable to SiC growth can therefore be reached around carbonaceous grains during the shallow emplacement of silicate melts or kimberlites and do not necessarily imply extremely localized oxygen-depleted regions in the mantle. Such reduced conditions can also explain the presence of elemental Si and iron-carbide inclusions in association with moissanite grains.

Key-words: moissanite, silicon carbide, carboreduction, mantle redox state, thermodynamic modeling.

1. Introduction

1.1. Mantle redox state

The evolution of mantle redox state and its heterogeneities are matter of a long standing debate (Frost & McCammon, 2008). The generally accepted picture is that most mantle rocks, including basaltic melts, are equilibrated at oxygen fugacity in the range FMQ−2 to FMQ + 0.5, expressed as log-unit relative to FMQ, the fayalite-magnetite-quartz redox buffer (Behrens & Gaillard, 2006; Frost & McCammon, 2008), and these conditions have been established probably 3.9 Ga ago (Canil, 2002). More reducing conditions – down to FMQ−4 (Woodland & Koch, 2003; McCammon & Kopylova, 2004) may be locally preserved, e.g. underneath cratons, as indicated by mantle xenoliths. This is suggested by experimental constraints indicating deep lithospheric roots and some regions of the asthenosphere being saturated in Fe-metal (Rohrbach et al., 2007). It would imply lowermost fO2 values at FMQ−6 (i.e. IW−1.5, where IW stands for the iron-wüstite redox buffer), but recent experimental recalibrations of redox equilibria in garnet peridotites (Stagno et al., 2013) suggest that the FMQ−4 should rather be the lowermost fO2 values for the upper mantle. It is therefore accepted that oxygen fugacity is decreasing with increasing depth in the upper mantle, but the magnitude of this effect seems to be moderate, remaining close to, but still definitively above the saturation in Fe-metal.

1.2. Moissanite occurrences

The redox conditions prevailing in the upper parts of the Earth mantle and crust make difficult the explanation of numerous findings of natural silicon carbide - moissanite - in very different geological settings (for reviews on SiC occurrences see, e.g. Kaminsky et al., 1968; Derkachenko et al., 1972; Lyakhovich, 1979; Marshintsev, 1990). Moissanite has been found as inclusions in diamonds (Jaques et al., 1989; Moore & Gurney, 1989; Leung et al., 1990; Klein-BenDavid et al., 2007), in mantle-derived magmatic rocks such as kimberlites (Bobrievich et al., 1957; Shiryaev et al., 2011), picritic traps (Kitaynik, 1958; Oleinikov et al., 1977; Iacono-Marziano et al., 2012b) and volcanic breccias (Bauer et al., 1963; Goshkov et al., 1995; Di Pierro et al., 2003, and many others). More enigmatic occurrences include high- and low-grade metamorphic rocks, limestones, pegmatites and chromitite pods within ophiolites (Gnoevaja & Grozdanov, 1965; Lyakhovich, 1967, 1979; Marshintsev,
1990 and references therein; Miyano et al., 1982; Shiryaev et al., 2008; Trumbull et al., 2009). An association of moissanite in serpentinite from ultrahigh-pressure (UHP) metamorphic rocks was described by Xu et al. (2008).

Information about moissanite petrological environment is limited, since the majority of finds are related to separate grains recovered from heavy fractions. In Si-rich rocks moissanite is sometimes found as intergrowth with quartz and alkali feldspars (Mineyeva & Kartenko, 1967; Leung et al., 1990). Intergrowth with quartz possibly results from partial oxidation of SiC and cannot really be used as a reliable criterion of syngenetic origin. Di Pierro et al. (2003) observed unidentified MgFe-silicates with FeO contents ranging between 3 and 8 wt% in contact with SiC. Moissanite from kimberlites is sometimes in association with calcite and chromite (Marshintsev, 1990). It was also observed in magnetite-olivine breccia in carbonatitic rocks (Glushkina et al., 1963). In summary, investigation of a large number of moissanite occurrences shows absence of preferred mineral phases associated with SiC.

Diamonds and kimberlites are important rocks in the discussion of moissanite occurrences. Indeed, the first reliable observation of natural moissanite was made in kimberlite (Bobrievich et al., 1957). Subsequently, rare moissanite inclusions in natural diamonds were discovered, in association with eclogitic garnet, peridotitic diopside, rutile, kappa-alumina, sanidine plus andradite (Moore & Gurney, 1989; Leung et al., 1990; Klein-BenDavid et al., 2007). A semi-amorphous K-Al-Si phase was observed in coexistence with moissanite both in diamonds (Leung et al., 1996) and as inclusion in SiC (Shiryaev et al., 2011). However, it is critically important to emphasise that SiC inclusions in diamonds are extremely rare (approx. 10 inclusions in total) in comparison with worldwide inventory of reliable moissanite discoveries and, therefore, attempts to relate moissanite exclusively to deep mantle are barely reasonable.

A recent detailed study of inclusions and trace elements of natural SiC (Shiryaev et al., 2011) shows that trace elements readily discriminate natural from synthetic SiC. Remarkably, trace elements in moissanite grains from various Siberian kimberlites and from Bulgarian limestones are broadly similar (Shiryaev et al., 2008). Grains of natural SiC of various origin often contain inclusions of highly reduced phases such as native Si (Marshintsev, 1990) and Fe-, Mg-, Ti-, Cr-silicides (Marshintsev, 1990; Di Pierro et al., 2003; Marshintsev et al., 1967; Mathez et al., 1995), which imply formation under extremely reducing conditions, well below the IW buffer that is commonly regarded as a lower limit in mantle jO2. This requires a mechanism for drastically lowering the jO2, at least locally.

The temperature of the moissanite formation might be bounded from observations of FeSi2 exsolved from Si inclusion in SiC as reported by Shiryaev et al. (2011). According to the low-pressure phase diagram (Kubaschewski, 1982), such exsolution occurs at temperatures lower than 937 °C. Therefore, one may expect that moissanite formation or at least nucleation took place in relatively hot environments.

### 1.3. How to make SiC, brief review of materials and Earth sciences

Published experiments show that silicon carbide can be formed in very different ways (e.g., Knippenberg, 1963; Derkachenko et al., 1972), thus suggesting that moissanite can be a polygenic mineral. Models of moissanite formation can be roughly divided into those favoring “high” or “low” pressures.

The “high”-pressure models are largely centered on moissanite inclusions in diamonds and from kimberlites and imply existence of extremely reduced mantle volumes that contrast with the average mantle redox state (e.g., Di Pierro et al., 2003; Trumbull et al., 2009). However, the presence of such mantle domains is still debatable and the HT-HP processes triggering moissanite formation in the lower mantle remain unspecified. Recently Bali et al. (2013) suggested that water (H2O) and hydrogen (H2) can be immiscible at mantle pressure, implying coexistence of H2-rich and water-rich fluids. Even if H2 is a reducing agent, immiscibility is an equilibrium process, implying that oxygen fugacity of these immiscible fluids must be similar. So H2-rich fluid is not necessarily a solution for making SiC at mantle pressures as one still needs to trigger extremely reducing conditions (see Section 1.4).

The “low”-pressure models include moissanite formation by serpenitisation (Mathez et al., 1995) and electrochemical synthesis in carbonate-silicate melts (Shiryaev et al., 2011). The serpenitisation mechanism might have been important for moissanite inclusions found in metamorphic serpentines (Xu et al., 2008). The electrochemical route is based on material-sciences experiments in which growth of SiC layers was achieved during electrochemical reactions in carbonate-silicate melts. Whereas this scenario is feasible for some occurrences, it is difficult to extend it to all moissanite finds.

On the basis of observation of relatively high moissanite concentration at contacts between carbonates and magmatic rocks, Mineyeva & Kartenko (1967) have suggested that moissanite is formed during emplacement of hot silicic melts into organics-rich carbonates. This scenario also explains isotopically light carbon common for moissanites. Similar interaction between low-pressure magma and carbonaceous matter was modelled by Iacono-Marziano et al. (2012b) to explain the formation of intrusive rocks rich in reduced Fe-metal and containing small amount of SiC (Ryabov & Lapkovsky, 2010). In fact, carbothermal reduction of silica at high temperatures with formation of SiC is a well-known phenomenon, being the base of Acheson process of industrial production of SiC for abrasives. The industrial Acheson process is usually realised at very high temperatures exceeding 2000 °C (e.g., Knippenberg, 1963). However, numerous experiments have shown that SiC can be produced via gas-phase reactions between SiO2 and graphite (e.g., Blumenthal et al., 1966; Klinger et al., 1966) or various clays with graphite (Mazzoni et al., 1992; Mazzoni & Aglietti, 1997a, 1997b) at temperatures as low as 1300 °C. SiC formation is favored at high silica contents and low temperatures. Iron and possibly other metals may catalyse
1.4. Required redox conditions for SiC

Despite a significant number of reliable reports of moissanite finds in many types of rocks, the fact that SiC formation requires extremely reducing conditions has fueled skepticism about most papers, with the exception of occurrences of moissanite and other reduced mineral suites in kimberlites. At equilibrium SiC can coexist with silicates only under conditions so reducing that their mantle origin has been questioned. The disruption of Si-O bonds to form Si-C ones indeed requires extremely oxygen-depleted environments. Thermodynamic calculations using the following equilibrium allows the $f_{O_2}$ defining the coexistence of moissanite and mantle minerals to be estimated:

$$\text{SiC} + \text{Mg}_2\text{SiO}_4 + \text{O}_2 = 2 \text{MgSiO}_3 + \text{C}. \quad (1)$$

Mathez et al. (1995) obtained oxygen fugacities that are 4 to 6 log units below IW buffer (IW being approx. FMQ-4) for calculations performed over a range of pressure-temperature conditions of 2–18 GPa and 1000–1800 K. High-pressure experiments by Ulmer et al. (1998) support predictions by Mathez et al. (1995).

In summary, oxygen-depleted conditions required for SiC stability are difficult to reconcile with the mantle redox state. At equilibrium, SiC may coexist only with Fe-free silicates (olivine, orthopyroxene and garnet), i.e. in assemblages similar to enstatite chondrites and those have never been observed in the Earth’s mantle. The SiC grains have therefore never been equilibrated with the coexisting Fe-Mg minerals even at hand-specimen scales. It must then reflect extremely local processes that never extended their equilibria beyond a couple of millimeters. In addition, the general paucity of oxidation products such as SiO$_2$ or silicon oxycarbides on the surface of moissanite grains (for review of SiC oxidation see Presser & Nickel, 2008) indicates that after their formation, the process of SiC grain re-equilibration with the surrounding phases was initiated only rarely. Therefore, a very important statement can be made here: the process responsible for formation of most moissanite grains must occur prior to the thermal quenching of the rocks, i.e. during the eruption/emplacement, in order to preserve such disequilibrium features.

In this report we provide results of thermodynamic calculations, giving support for a moissanite formation in very different geological settings by a process similar to the industrial Acheson process: $3\text{C} + \text{SiO}_2 = \text{SiC} + 2 \text{CO}$. We show that SiC formation can occur during the ultimate steps of ascent of degassing, C-saturated silicate rocks or melts, when pressure is lower than 100 bars. At these conditions, the redox buffering by carbon can locally impose $f_{O_2}$ similar to IW-6, thus making SiC formation possible.

2. Methods and results

2.1. Thermodynamic model

We first model the oxygen fugacity imposed by carbon-gas equilibria at low pressures (3 kbar to 1 bar) in the C–O system. We assumed temperature of 1300 °C, a temperature sufficient to produce synthetic SiC in experiments and not uncommon for some (e.g., picritic) magmas (e.g., Herzberg et al., 2010, and references therein). Note that moissanite was indeed observed in picritic traps (e.g., Kitaynik, 1958; Oleinikov et al., 1977). The computed equilibria are:

$$\text{C} + \text{O}_2 = \text{CO}_2$$
$$\text{which gives}$$
$$f_{O_2} = f_{\text{CO}_2}/K_{f(2)}$$

and

$$\text{C} + \frac{1}{2} \text{O}_2 = \text{CO}$$
$$\text{which gives}$$
$$f_{O_2} = f_{\text{CO}}/K_{f(4)}.$$  

In all cases, $K_X$ refers to the thermodynamic constant of the equilibrium (X) (see compilation in Symonds & Red, 1993, for the thermodynamic constants) and “$f$” refers to the fugacity of gas species (see Shi & Saxena, 1992, for a complete description). In a recent analysis of gas-melt equilibria at temperature-pressure conditions equivalent to 1200–1400 °C, 1 bar-10 kbar, Iacono-Marziano et al. (2012a) have concluded that gas species (CO$_2$–H$_2$O) must behave as an ideal mixture of ideal gases. For our calculation at $P < 3$ kbar and $T = 1300$ °C, we therefore simplified our fluid system as an ideal mixture of ideal gases (i.e. fugacities are equivalent to partial pressures). Combining (3) and (4) with the constraints that the partial pressures of the gas compounds sum to the total pressure,

$$P(\text{CO}_2) + P(\text{CO}) = P_{\text{tot}}$$

we obtained that $f_{O_2}$-pressure relationships must follow the equation:

$$f_{O_2} = K_{f(4)}/K_{f(2)} f_{O_2}^{1/2} = P_{\text{tot}}/K_{f(2)}.$$  

The resolution of equation (7) as a function of pressure results in the plot shown in Fig. 1a. Due to the strong decrease in CO$_2$ partial pressure, $P(\text{CO}_2)$, with decreasing pressure, equilibria (2) and (4) are shifted to the right and oxygen fugacity at graphite saturation decreases nearly proportionally to total pressure.

The second calculation considers a system gas-melt-graphite with the stable volatile species in a C–O–H system (see Gaillard & Scaillet, 2009, for details of gas-melt equilibria, Fig. 1b). In that case, equilibrium (2) and (4) are treated together with the reaction of water dissociation and methane formation:

$$\text{H}_2\text{O} = \text{H}_2 + \frac{1}{2} \text{O}_2$$  

the reaction (Lee & Cutler, 1975). An experimental synthesis of SiC by reaction of SiO$_2$ + Na$_2$CO$_3$ + C (Blumenthal et al., 1966) is relevant to the suggestion of Mineyeva & Kartenko (1967) and shows that, in case of molten silicates, the reaction is very fast during initial stages, but slows down rapidly when individual carbon particles are consumed.
and CO become dominant. As a result, tics of SiC formation may pressure evolution of such a system does P is slightly more reduced f is taken from Gaillard ¼ CH CH during depressurisation of carbon-saturated magma. As 2 et al. CO abundances decrease H2 and 3 wt% H2 in contents (both fixed at 3 f C is shown as a CO/C14 (9) C, which is based on H2/C14 (10) et al., 2010). The conditions (Morizet et al. 2010). The calculations shown in Fig. 1 were performed for a temperature of 1300 °C, which is based on experimental works on SiC formation by carboreduction process and on moissanite observations in picritic rocks. It is important to note that carboreduction is a viable mechanism for SiC formation even at lower temperatures, as shown on Fig. 3, if the pressure is low enough. However, kinetics of SiC formation may be very slow at temperatures as low as 1100 °C, thus making moissanite formation less likely.

C + 2 H2 = CH4. (9)

The equilibrium constant for these reactions can be found in Symonds & Red (1993). Due to the increase in the chemical complexity of the system, equation (6) becomes:

\[ P(\text{CO}_2) + P(\text{CO}) + P(\text{CH}_4) + P(\text{H}_2\text{O}) + P(\text{H}_2) = P_{\text{tot}}. \] (10)

The melt considered is basaltic in composition. Gas-melt equilibrium for CO2+H2O is taken from Iacono-Marziano et al. (2012a); H2 solubility is taken from Gaillard et al. (2003) and other species are considered as insoluble in the melt at these P-T conditions (Morizet et al., 2010). The implementation of gas-melt equilibria with graphite-redox equilibrium (eq. 2 and 4) is described in detail in Iacono-Marziano et al. (2012b). The amount of H2O and CO2 in the system is 3 wt% for both species. The amount of graphite and the amount of gas calculated as a function of pressure is shown in Fig. 2. During the entire decompression, the gas-melt system remains graphite saturated (graphite content at 300 MPa is 3.5 wt% and gas percentage is 3.2 wt%). The fO2 pressure evolution of such a system does not differ much from that occurring in a simple C–O system. Figure 1a shows that fO2 is slightly more reduced essentially as a consequence of a dilution effect: CO and CO2 are diluted by CH4, H2O and H2, which shift equilibria (2) and (4) to the right-hand side.

In summary, the trends shown in Fig. 1 reflect the redox buffering by carbon-saturated systems upon decompression. This picture remains true whatever the phase coexisting with carbon (gas, melt, solids) provided that carbon is buffering fO2. Note that Sato (1978) already mentioned the possibility of such buffering effect of carbon on magma redox state with application to the Moon (see also Nicholis & Rutherford, 2009 on a similar topic).

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At surface pressures, oxygen fugacity reaches values similar to IW-6, which are required to precipitate SiC from silica-bearing minerals such as olivine that coexists with carbon (Figs. 1b and 3). Fe-metal can precipitate at \( f_{O_2} \) lower than IW-2 (Gaillard & Scaillet, 2009), which is possible when pressure is lower than 100 bars (see Iacono-Marziano et al., 2012b, for additional simulation). Low-pressure local redox buffering by carbon is a likely explanation for the presence of reduced species in igneous rocks that do not require extremely reduced mantle regions, which are otherwise unexpected. Depending on the amount of carbon in the rock, the carbon buffering can be local or global. The Disko Island and the Siberian Traps cases illustrated in Iacono-Marziano et al. (2012b) correspond to a global C-buffering that affects large volumes of magma (intrusion of basalts into coal-rich sediments). In the case of small amount of graphite, C-redox buffering is affecting only the narrow vicinity of carbon-bearing phases and is not imposing a redox change of the entire rock. Temperature changes are expected to moderately affect the redox trend of Fig. 1a. The decrease in oxygen with decreasing pressure will become more pronounced as CH\(_4\) will increasingly be stable. The fraction of both gaseous CO and CO\(_2\) will then be decreased which implies slightly lower \( f_{O_2} \) at graphite saturation.

2.2. Formation of moissanite at C-saturation

At low pressures in system with redox conditions controlled by carbon-buffering, SiC can easily be formed as \( f_{O_2} \) are lower than IW-4. This process is moderately affected by temperature and can operate in solids or melts coexisting with carbon. What is needed is a source of silicon at carbon-saturation under low pressures (<20 bars). Silica activity must then play a role in stabilizing SiC. Equilibrium (1) indicates that in addition to low \( f_{O_2} \), SiC formation is favored by elevated silica activities. The association of SiC with carbonated melts (Glushkina et al., 1963; Gnoevaja & Grozdanov, 1965; Shiryaev et al., 2011) that are well-known for their low silica activity (Luth, 2009), may then seem surprising. Furthermore, as reviewed in Section 1.2., no typical mineral association is preferentially found with SiC. Silicate minerals, carbonates or oxides have been found so that no general reaction mechanisms can be proposed.

The most generic reaction forming SiC could be:

\[
6 \text{ C} + 4 \text{ MgSiO}_3 \rightarrow 2 \text{ SiC} + 6 \text{ CO} + 2 \text{ Mg}_2\text{SiO}_4
\]

(11)
as olivine and pyroxene are present in many SiC-bearing rocks. It is known that excessive partial pressure of CO suppresses silicate reduction in this process, which is qualitatively similar to the Acheson one (Derkachenko et al., 1972). Therefore, a requirement for this process to generate appreciable quantities of SiC is that the produced CO is evacuated from the local system. Permeability of rocks and melts in respect to CO gas or high CO solubility in them should, therefore, play an important role for moissanite formation. Permeability of extrusive rocks during emplacement at surface is usually elevated enough to ensure gas removal. This feature is enhanced by high volatile contents.

On the other hand, if reaction (11) can be justified as olivine and pyroxene are abundant in SiC-bearing rocks, Fe-free forsterite is never found in coexistence with SiC. Given the absence of systematic mineral association with SiC, we could suggest a gas-phase reaction such as:

\[
\text{SiO}_{\text{gas}} + 2\text{C} = \text{SiC} + \text{CO}_{\text{gas}}.
\]

(12)

This mechanism has the great advantage of leaving no systematic or typical mineralogical assemblages associated with SiC as recognized in Section 1.2. We discuss below relationships previously recognized between SiO and SiC formation.

2.3. Formation of highly reduced phases together with moissanite

As mentioned in the Introduction, moissanite is often accompanied by inclusions of highly reduced phases such as elemental silicon, various carbides and silicides. Reduction of SiO\(_2\) to Si-metal requires extremely low values of \( f_{O_2} \), which can not be attained considering carbon redox buffering (\( f_{O_2} < \) IW-9 considering \( a(\text{SiO}_2) = 1 \)). However, formation of Si-metal from gaseous SiO (see reaction below) is feasible at \( f_{O_2} \) lower than IW-4 if silicon-monoxide activity \( a(\text{SiO}) \) is close to unity:

\[
\text{SiO}_{\text{gas}} = \text{Si}_{\text{solid}} + \frac{1}{2} \text{O}_2.
\]

(13)
The \( f_{O_2} \) corresponding to the above equilibrium is within the range of \( f_{O_2} \) imposed by carbon-saturation at low pressure (Fig. 1). It is therefore possible that graphite saturation at low pressure generates SiC together with Si and Si-Fe metal grains. This demands high SiO activities. According to kinetics experiments (Mendybaev et al., 2002), redox conditions favorable to SiC growth also favors vaporization of silicate in SiO form at 1 bar pressure in atmosphere composed of H–C–O species. At magmatic temperatures (1300 °C) and \( f_{O_2} \) in the range IW-3 to IW-6, SiO can constitute a significant
fraction of the gas (at SiO₂ saturation) (Mendybaev et al., 2002). We can therefore not exclude that Si grains result from local equilibrium processes imposing high SiO₂ activities. Similarly to SiC grains that are clearly not equilibrated with the surrounding Fe-bearing silicates, in terms of fO₂, it is also not equilibrated with respect to α(SiO₂). Furthermore, rapid cooling accompanying lava emplacements may contribute to nucleate Si-grains by condensation of gaseous SiO₂.

Eruptive processes implying adiabatic decompression may give rise to SiC formation by a similar mechanism, which may explain moissanite finds in volcanic breccia (Bauer et al., 1963) and rocks (Di Pierro et al., 2003) as well as in mantle xenoliths from subduction-related settings (Ishimaru et al., 2009). Intrusion of mafic magma into carbonaceous rocks in Siberian Traps or at the famous Disko Island are also remarkable field occurrences of SiC (Kitaynik, 1958; Oleinikov et al., 1977; Ryabov et al., 2010; Iacono-Marziano et al., 2012a); but the latter implies a bulk equilibrium (with all the extrusive rocks being equilibrated with oxygen fugacity as low as IW-4). In contrast, the occurrence of SiC as described in the literature of mantle rocks most likely involves local equilibrium operating during the emplacement of mafic rocks at low pressure.

3. Conclusion

Redox buffering by carbon upon decompression to atmospheric pressure triggers extremely reducing conditions that can explain the sporadic but enigmatic occurrence of oxygen-depleted phases such as SiC, Fe, or even Si in igneous rocks that are observed in very different geodynamic settings. This avoids calling upon excessively reducing mantle regions that are otherwise unexpected in existing models of mantle redox state. This process is operating as carbon is remaining in the system but is also consuming carbon, implying that the redox reaction is stopped as C is exhausted. At low pressure we can expect fO₂ as low as IW-6 in such C-saturated systems, whether molten or not, because carbon buffering would impose such low fO₂ whatever the coexisting phases (melts or minerals). Redox buffering by carbon at low pressure is a potentially important mechanism in rock-forming processes, including heating and melting of chondrites, which has been poorly considered so far.

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References

Kitaynik A.F. (1958): Moissanite from the traps of the Siberian platform. in “Geology and ore deposits of Eastern Siberia” Iss. 3(24), Irkutsk.
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